

SCBS145R-MAY 1992-REVISED AUGUST 2007

SN54LVTH16374... WD PACKAGE

### FEATURES

•	Members of the Texas Instruments Widebus™ Family	SN74LVTH16374 DGG OR DL PAC (TOP VIEW)	
•	State-of-the-Art Advanced BiCMOS Technology (ABT) Design for 3.3-V Operation and Low Static-Power Dissipation	10E 1 48 1CLK 1Q1 2 47 1D1	
•	Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V <sub>CC</sub> )	1Q2 [] 3 46 [] 1D2 GND [] 4 45 [] GND 1Q3 [] 5 44 [] 1D3	
•	Support Unregulated Battery Operation Down to 2.7 V	$1Q4 \begin{bmatrix} 0 & 44 \\ 6 & 43 \end{bmatrix} 1D4 V_{CC} \begin{bmatrix} 7 & 42 \end{bmatrix} V_{CC}$	
•	Typical V <sub>OLP</sub> (Output Ground Bounce) <0.8 V at V <sub>CC</sub> = 3.3 V, T <sub>A</sub> = 25°C	1Q5 [] 8 41 ] 1D5 1Q6 [] 9 40 ] 1D6	
•	Ioff and Power-Up 3-State Support Hot Insertion	GND [] 10 39 [] GND	
•	Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors	1Q7 [] 11 38 [] 1D7 1Q8 [] 12 37 [] 1D8	
•	Distributed V <sub>cc</sub> and GND Pins Minimize High-Speed Switching Noise	2Q1 [ 13 36 ] 2D1 2Q2 [ 14 35 ] 2D2	
•	Flow-Through Architecture Optimizes PCB Layout	GND [] 15 34 ] GND 2Q3 [] 16 33 ] 2D3	
•	Latch-Up Performance Exceeds 500 mA Per JESD 17	2Q4 [] 17 32 [] 2D4 V <sub>CC</sub> [] 18 31 [] V <sub>CC</sub>	
•	ESD Protection Exceeds JESD 22	2Q5	
	<ul> <li>2000-V Human-Body Model (A114-A)</li> </ul>	GND 21 28 GND	
	<ul> <li>200-V Machine Model (A115-A)</li> </ul>	2Q7 <b>2</b> 2 27 2D7	
		2Q8 23 26 2D8	
		2 <del>0E</del> [24 25] 2CLK	

### **DESCRIPTION/ORDERING INFORMATION**

The 'LVTH16374 devices are 16-bit edge-triggered D-type flip-flops with 3-state outputs designed for low-voltage (3.3-V) V<sub>CC</sub> operation, but with the capability to provide a TTL interface to a 5-V system environment. These devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

These devices can be used as two 8-bit flip-flops or one 16-bit flip-flop. On the positive transition of the clock (CLK), the Q outputs of the flip-flop take on the logic levels set up at the data (D) inputs.

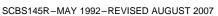
A buffered output-enable ( $\overline{OE}$ ) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without need for interface or pullup components.

OE does not affect internal operations of the flip-flop. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.



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### **DESCRIPTION/ORDERING INFORMATION (CONTINUED)**

When  $V_{CC}$  is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for hot-insertion applications using  $I_{off}$  and power-up 3-state. The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

T <sub>A</sub>	PACKAGE	(1)(2)	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	FBGA – GRD	Deal of 4000	SN74LVTH16374GRDR	11074	
	FBGA – ZRD (Pb-free)	Reel of 1000	SN74LVTH16374ZRDR	— LL374	
		Tub ( 05	SN74LVTH16374DL		
		Tube of 25	74LVTH16374DLG4	1.)/TU40074	
4000 to 0500	SSOP – DL	Deal of 4000	SN74LVTH16374DLR	LVTH16374	
–40°C to 85°C		Reel of 1000	74LVTH16374DLRG4		
	TOCOD DOO	Deal of 2000	SN74LVTH16374DGGR	1)/TU40074	
	TSSOP – DGG	Reel of 2000	74LVTH16374DGGRG4	LVTH16374	
	VFBGA – GQL	Deal of 4000	SN74LVTH16374KR	11074	
	VFBGA – ZQL (Pb-free)	Reel of 1000	SN74LVTH16374ZQLR	- LL374	
–55°C to 125°C	to 125°C CFP – WD Tube		SNJ54LVTH16374WD	SNJ54LVTH16374WD	

#### **ORDERING INFORMATION**

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.



**GQL OR ZQL PACKAGE** 

(TOP VIEW)

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**GRD OR ZRD PACKAGE** 

(TOP VIEW)

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#### TERMINAL ASSIGNMENTS<sup>(1)</sup> (56-Ball GQL/ZQL Package)

	1	2	3	4	5	6
Α	1 <mark>0E</mark>	NC	NC	NC	NC	1CLK
В	1Q2	1Q1	GND	GND	1D1	1D2
С	1Q4	1Q3	V <sub>CC</sub>	V <sub>CC</sub>	1D3	1D4
D	1Q6	1Q5	GND	GND	1D5	1D6
Е	1Q8	1Q7			1D7	1D8
F	2Q1	2Q2			2D2	2D1
G	2Q3	2Q4	GND	GND	2D4	2D3
н	2Q5	2Q6	V <sub>CC</sub>	V <sub>CC</sub>	2D6	2D5
J	2Q7	2Q8	GND	GND	2D8	2D7
K	2 <mark>0E</mark>	NC	NC	NC	NC	2CLK

(1) NC – No internal connection

#### TERMINAL ASSIGNMENTS<sup>(1)</sup> (54-Ball GRD/ZRD Package)

	1	2	3	4	5	6
Α	1Q1	NC	1 <del>0E</del>	1CLK	NC	1D1
В	1Q3	1Q2	NC	NC	1D2	1D3
С	1Q5	1Q4	V <sub>CC</sub>	V <sub>CC</sub>	1D4	1D5
D	1Q7	1Q6	GND	GND	1D6	1D7
Е	2Q1	1Q8	GND	GND	1D8	2D1
F	2Q3	2Q2	GND	GND	2D2	2D3
G	2Q5	2Q4	V <sub>CC</sub>	V <sub>CC</sub>	2D4	2D5
Н	2Q7	2Q6	NC	NC	2D6	2D7
J	2Q8	NC	2 <mark>0E</mark>	2CLK	NC	2D8

(1) NC - No internal connection

#### FUNCTION TABLE (EACH FLIP-FLOP)

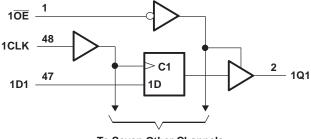
	INPUTS	OUTPUT	
OE	CLK	D	Q
L	↑	Н	Н
L	1	L	L
L	H or L	Х	<b>Q</b> <sub>0</sub>
Н	Х	Х	Z

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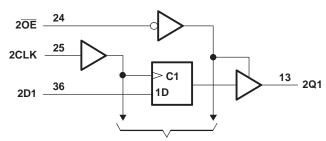
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#### LOGIC DIAGRAM (POSITIVE LOGIC)



To Seven Other Channels



To Seven Other Channels

Pin numbers shown are for the DGG, DL, and WD packages.

#### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V	
VI	Input voltage range <sup>(2)</sup>	range <sup>(2)</sup> applied to any output in the high-impedance or power-off state <sup>(2)</sup> applied to any output in the high state <sup>(2)</sup> ny output in the low state ny output in the high state <sup>(3)</sup> SN54LVTH16374 SN54LVTH16374 SN54LVTH16374				
Vo	Voltage range applied to any output in the high-in	npedance or power-off state <sup>(2)</sup>	-0.5	7	V	
Vo	Voltage range applied to any output in the high st					
	Ourseast into any output in the law state	SN54LVTH16374		96		
lo	Current into any output in the low state	SN74LVTH16374		128	mA	
	Ourseast into any output in the high state (3)	SN54LVTH16374		48	mA	
I <sub>O</sub>	Current into any output in the high state <sup>(3)</sup>		64			
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA	
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA	
		DGG package		70		
0		DL package		63	°C/W	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	GQL/ZQL package		42		
		GRD/ZRD package		36		
T <sub>stg</sub>	Storage temperature range	· · ·	-65	150	°C	

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(3) This current flows only when the output is in the high state and  $V_0 > V_{CC}$ .

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

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### **Recommended Operating Conditions**<sup>(1)</sup>

			SN54LVTH	16374	SN74LVTH	16374	UNIT
			MIN	MAX	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2.7	3.6	2.7	3.6	V
V <sub>IH</sub>	High-level input voltage		2		2		V
V <sub>IL</sub>	Low-level input voltage			0.8		0.8	V
VI	Input voltage			5.5		5.5	V
I <sub>OH</sub>	High-level output current			-24		-32	mA
I <sub>OL</sub>	Low-level output current			48		64	mA
Δt/Δv	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
$\Delta t / \Delta V_{CC}$	Power-up ramp rate		200		200		µs/V
T <sub>A</sub>	Operating free-air temperature		-55	125	-40	85	°C

(1) All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

	DAMETED	TEST OF	NDITIONS	SN54	LVTH16374	SN74LVTH163	374	UNIT
P/	RAMETER	TEST CC	ONDITIONS	MIN	TYP <sup>(1)</sup> MAX	MIN TYP <sup>(1)</sup>	MAX	UNIT
V <sub>IK</sub>		V <sub>CC</sub> = 2.7 V,	I <sub>I</sub> = -18 mA		-1.2		-1.2	V
		$V_{\rm CC}$ = 2.7 V to 3.6 V,	I <sub>OH</sub> = −100 μA	V <sub>CC</sub> - 0.2		V <sub>CC</sub> - 0.2		
V <sub>OH</sub>		V <sub>CC</sub> = 2.7 V,	I <sub>OH</sub> = –8 mA	2.4		2.4		V
on			I <sub>OH</sub> = -24 mA	2				
		$V_{CC} = 3 V$	I <sub>OH</sub> = -32 mA			2		
		V 07V	I <sub>OL</sub> = 100 μA		0.2		0.2	
		$V_{CC} = 2.7 V$	I <sub>OL</sub> = 24 mA		0.5		0.5	
V			I <sub>OL</sub> = 16 mA		0.4		0.4	V
V <sub>OL</sub>		V 2.V	I <sub>OL</sub> = 32 mA		0.5		0.5	V
		$V_{CC} = 3 V$	I <sub>OL</sub> = 48 mA		0.55			
			I <sub>OL</sub> = 64 mA				0.55	
		V <sub>CC</sub> = 0 or 3.6 V,	V <sub>I</sub> = 5.5 V		10		10	
I <sub>I</sub>	Control inputs	V <sub>CC</sub> = 3.6 V,	$V_{I} = V_{CC}$ or GND		±1		±1	μA
•1	Data innuta	Vac = 3.6 V	$V_{I} = V_{CC}$		1		1	·
	Data inputs	V <sub>CC</sub> = 3.6 V	V <sub>1</sub> = 0		-5		-5	
I <sub>off</sub>	-1-	$V_{CC} = 0,$	$V_{\rm I}$ or $V_{\rm O}$ = 0 to 4.5 V				±100	μA
	Data inputs	V <sub>CC</sub> = 3 V	V <sub>I</sub> = 0.8 V	75		75		
I <sub>I(hold)</sub>			V <sub>I</sub> = 2 V	-75		-75		μA
"I(noia)		V <sub>CC</sub> = 3.6 V, <sup>(2)</sup>	V <sub>I</sub> = 0 to 3.6 V					μπ
I <sub>OZH</sub>	-1-	V <sub>CC</sub> = 3.6 V,	$V_{O} = 3 V$		5		5	μA
I <sub>OZL</sub>		V <sub>CC</sub> = 3.6 V,	V <sub>O</sub> = 0.5 V		-5		-5	μA
I <sub>OZPU</sub>		$\frac{V_{CC}}{OE} = 0$ to 1.5 V, V <sub>O</sub> = $\overline{OE} = $ don't care	= 0.5 V to 3 V,		±100 <sup>(3)</sup>		±100	μA
I <sub>OZPD</sub>		$\frac{V_{CC}}{OE}$ = 1.5 V to 0, V <sub>O</sub> = OE = don't care	= 0.5 V to 3 V,		±100 <sup>(3)</sup>		±100	μA
		V <sub>CC</sub> = 3.6 V,	Outputs high		0.19		0.19	
I <sub>CC</sub>		$I_{O} = 0,$	Outputs low		5		5	mA
		$V_{I} = V_{CC}$ or GND	Outputs disabled		0.19		0.19	
$\Delta I_{CC}^{(4)}$		$V_{CC} = 3 V \text{ to } 3.6 V,$ One input at $V_{CC} = 0$ Other inputs at $V_{CC}$ o	.6 V, r GND		0.2		0.2	mA
CI		$V_{I} = 3 V \text{ or } 0$			3	3		pF
Co		$V_0 = 3 V \text{ or } 0$			9	9		pF

(1) All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ . (2) This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

On products compliant to MIL-PRF-38535, this parameter is not production tested. (3)

(4) This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V<sub>CC</sub> or GND.

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### **Timing Requirements**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			S	N54LVT	H16374		S	N74LV	TH16374		
			V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> =	$V_{\rm CC} = 2.7 \text{ V}$ $V_{\rm CC} = \pm 0$		3.3 V 3 V	V <sub>CC</sub> = 2.7 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>clock</sub>	Clock frequency			160		160		160		160	MHz
tw	Pulse duration, CLK high or low		3		3		3		3		ns
t <sub>su</sub>	Setup time, data before CLK↑	High or low	2.9		3.3		1.8		2		ns
t <sub>h</sub>	Hold time, data after CLK↑	High or low	0.8		0.2		0.8		0.1		ns

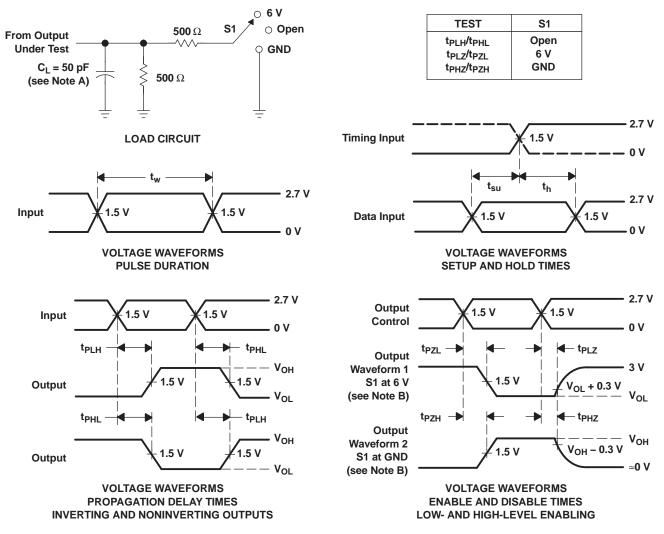
### **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 1)

		SN54LVTH16374 SN74LVTH16374										
PARAMETER	FROM (INPUT)	TO (OUTPUT)		V <sub>CC</sub> = 3.3 V ± 0.3 V		$V_{CC}$ = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V			2.7 V	UNIT
			MIN	MAX	MIN	MAX	MIN	TYP <sup>(1)</sup>	MAX	MIN	MAX	
f <sub>max</sub>			160		160		160			160		MHz
t <sub>PLH</sub>	CLK	Q	1.4	5.6		6.2	1.9	3	4.5		5.2	ns
t <sub>PHL</sub>	CLK	Q	1.7	4.8		5	2.1	2.9	4		4.2	115
t <sub>PZH</sub>	OE	Q	1	5.6		6.4	1.5	2.8	4.5		5.4	ns
t <sub>PZL</sub>	OL	Q	1.4	5.5		6.2	1.5	2.8	4.4		5	115
t <sub>PHZ</sub>	OE	Q	1	6.4		6.9	2.4	3.5	5		5.4	20
t <sub>PLZ</sub>	UE	Q	1.7	5		5.2	2	3.2	4.6		4.8	ns
t <sub>sk(LH)</sub>									0.5			ns
t <sub>sk(HL)</sub>									0.5			115

(1) All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.

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PARAMETER MEASUREMENT INFORMATION

IEXAS

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NOTES: A.  $C_L$  includes probe and jig capacitance.

- Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. В. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>Q</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.

#### Figure 1. Load Circuit and Voltage Waveforms



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### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
5962-9564701QXA	ACTIVE	CFP	WD	48	1	TBD	Call TI	Call TI	
74LVTH16374DGGRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
74LVTH16374DLRG4	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH16374DGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH16374DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH16374DLG4	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH16374DLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH16374GQLR	LIFEBUY	BGA MICROSTAR JUNIOR	GQL	56	1000	TBD	SNPB	Level-1-240C-UNLIM	
SN74LVTH16374GRDR	NRND	BGA MICROSTAR JUNIOR	GRD	54	1000	TBD	SNPB	Level-1-240C-UNLIM	
SNJ54LVTH16374WD	ACTIVE	CFP	WD	48	1	TBD	A42	N / A for Pkg Type	

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.



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Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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#### OTHER QUALIFIED VERSIONS OF SN54LVTH16374, SN74LVTH16374 :

Catalog: SN74LVTH16374

Enhanced Product: SN74LVTH16374-EP, SN74LVTH16374-EP

• Military: SN54LVTH16374

#### NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION

#### REEL DIMENSIONS

Texas Instruments





TAPE AND REEL INFORMATION

#### TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH16374DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	15.8	1.8	12.0	24.0	Q1
SN74LVTH16374DLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1
SN74LVTH16374GQLR	BGA MI CROSTA R JUNI OR	GQL	56	1000	330.0	16.4	4.8	7.3	1.45	8.0	16.0	Q1
SN74LVTH16374GRDR	BGA MI CROSTA R JUNI OR	GRD	54	1000	330.0	16.4	5.8	8.3	1.55	8.0	16.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

14-Jul-2012



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH16374DGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74LVTH16374DLR	SSOP	DL	48	1000	367.0	367.0	55.0
SN74LVTH16374GQLR	BGA MICROSTAR JUNIOR	GQL	56	1000	333.2	345.9	28.6
SN74LVTH16374GRDR	BGA MICROSTAR JUNIOR	GRD	54	1000	333.2	345.9	28.6

## **MECHANICAL DATA**

MCFP010B - JANUARY 1995 - REVISED NOVEMBER 1997

#### **CERAMIC DUAL FLATPACK**

#### WD (R-GDFP-F\*\*)

48 LEADS SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. This package can be hermetically sealed with a ceramic lid using glass frit.
  - D. Index point is provided on cap for terminal identification only
  - E. Falls within MIL STD 1835: GDFP1-F48 and JEDEC MO-146AA
    - GDFP1-F56 and JEDEC MO-146AB



GRD (R-PBGA-N54)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

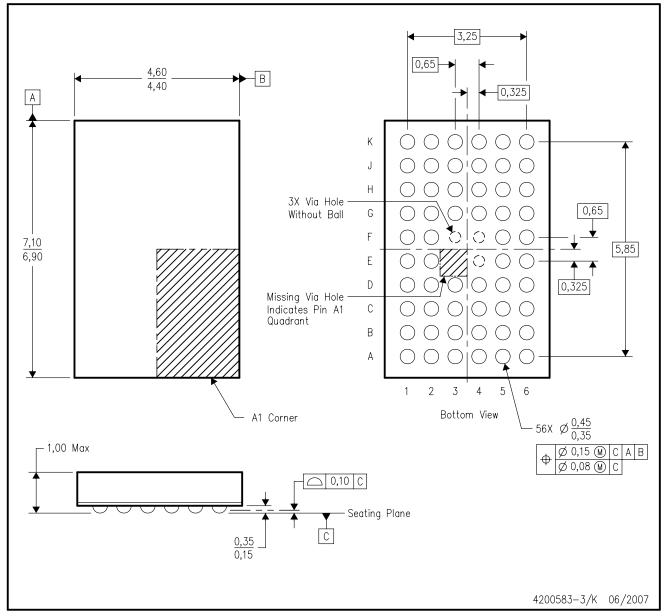
Falls within JEDEC MO-205 variation DD.

D. This package is tin-lead (SnPb). Refer to the 54 ZRD package (drawing 4204760) for lead-free.



GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



# **MECHANICAL DATA**

MSSO001C - JANUARY 1995 - REVISED DECEMBER 2001

#### PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN

DL (R-PDSO-G\*\*)



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MO-118



# **MECHANICAL DATA**

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

#### DGG (R-PDSO-G\*\*)

#### PLASTIC SMALL-OUTLINE PACKAGE

**48 PINS SHOWN** 



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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